# **74AUP1T57**

Low-power configurable gate with voltage-level translator

Rev. 6 — 26 May 2021 Product data sheet

### 1. General description

The 74AUP1T57 is a configurable multiple function gate with level translating, Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND. Low threshold Schmitt trigger inputs allow these devices to be driven by 1.8 V logic levels in 3.3 V applications.

This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 2.3 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- · High noise immunity
- Low static power consumption; I<sub>CC</sub> = 1.5 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP1T57GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363					
74AUP1T57GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					
74AUP1T57GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115					
74AUP1T57GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202					



### Low-power configurable gate with voltage-level translator

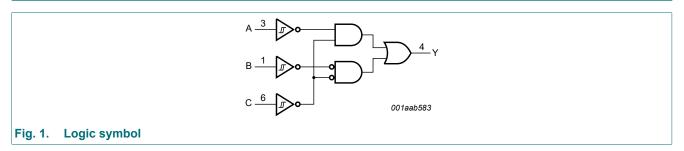
# 4. Marking

#### Table 2. Marking

Type number	Marking code [1]
74AUP1T57GW	a7
74AUP1T57GM	a7
74AUP1T57GN	a7
74AUP1T57GS	a7

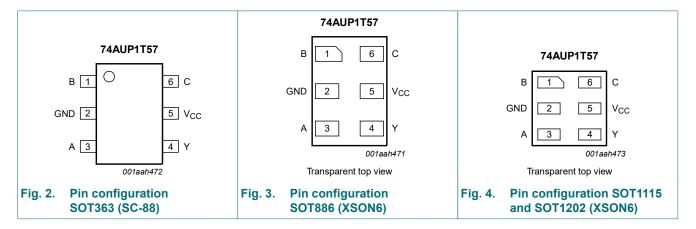
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



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### Low-power configurable gate with voltage-level translator

# 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

# 7. Functional description

### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input			Output
С	В	A	Υ
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

### 7.1. Logic configurations

**Table 5. Function selection table** 

Logic function	Figure
2-input AND	see Fig. 5
2-input AND with both inputs inverted	see Fig. 8
2-input NAND with inverted input	see Fig. 6 and Fig. 7
2-input OR with inverted input	see Fig. 6 and Fig. 7
2-input NOR	see Fig. 8
2-input NOR with both inputs inverted	see Fig. 5
2-input XNOR	see Fig. 9
Inverter	see Fig. 10
Buffer	see Fig. 11

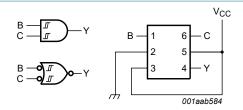


Fig. 5. 2-input AND gate or 2-input NOR gate with both inputs inverted

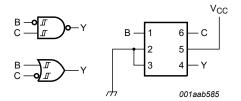


Fig. 6. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

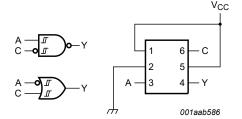


Fig. 7. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

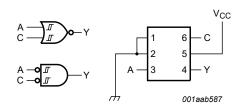


Fig. 8. 2-input NOR gate or 2-input AND gate with both inputs inverted

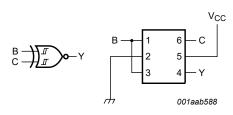


Fig. 9. 2-input XNOR gate

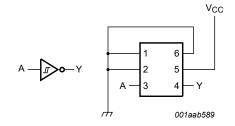


Fig. 10. Inverter

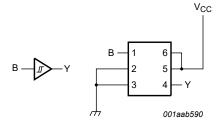


Fig. 11. Buffer

#### Low-power configurable gate with voltage-level translator

# 8. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

<sup>[2]</sup> For SOT363 (SC-88) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

### Low-power configurable gate with voltage-level translator

# 10. Static characteristics

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
V <sub>T+</sub>	positive-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.16	V
V <sub>T-</sub>	negative-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.23	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.25	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	0.10	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.1	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	1.2	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$	[1] -	-	-	μA
		V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A	[2] -	-	-	μA
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.8	-	pF
Co	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C		l			
V <sub>T+</sub>	positive-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.10	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.15	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 2.3 $V$ to 3.6 $V$	-	-	0.1	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_I$ or $V_O$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μΑ
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.5	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	1.5	μA
ΔI <sub>CC</sub>	additional supply current	$V_{CC}$ = 2.3 V to 2.7 V; $I_{O}$ = 0 A [1]	-	-	4	μΑ
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_O = 0 \text{ A}$ [2]	-	-	12	μA

### Low-power configurable gate with voltage-level translator

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C				ı	
V <sub>T+</sub>	positive-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold	V <sub>CC</sub> = 2.3 V to 2.7 V	0.33	-	0.64	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	0.46	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.10	-	0.60	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.15	-	0.56	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V	-	-	3.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$ [1]	-	-	7	μΑ
		V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A [2]	-	-	22	μΑ

# 11. Dynamic characteristics

### **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

Symbol	Parameter	Conditions	25 °C		25 °C -40 °C to -40 °C to +85 °C +125 °C					Unit
				Typ[1]	Max	Min	Max	Min	Max	
$V_{CC} = 2$ .	3 V to 2.7 V; V <sub>I</sub> = 1	I.65 V to 1.95 V								
t <sub>pd</sub>	propagation	A, B, C to Y; see <u>Fig. 12</u> [2]								
	delay	C <sub>L</sub> = 5 pF	2.1	3.6	5.5	0.5	6.8	0.5	7.5	ns
		C <sub>L</sub> = 10 pF	2.6	4.1	6.2	1.0	7.9	1.0	8.7	ns
		C <sub>L</sub> = 15 pF	2.9	4.6	6.8	1.0	8.7	1.0	9.6	ns
		C <sub>L</sub> = 30 pF	3.8	5.8	8.2	1.5	10.8	1.5	11.9	ns

One input at 0.3 V or 1.1 V, other input at  $V_{CC}$  or GND. One input at 0.45 V or 1.2 V, other input at  $V_{CC}$  or GND.

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Symbol	Parameter	Parameter Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	Min	Max	
V <sub>CC</sub> = 2.	3 V to 2.7 V; V <sub>I</sub>	= 2.3 V to 2.7 V								
t <sub>pd</sub>	propagation	A, B, C to Y; see Fig. 12 [2]								
	delay	C <sub>L</sub> = 5 pF	1.7	3.4	5.4	0.5	6.0	0.5	6.6	ns
		C <sub>L</sub> = 10 pF	2.1	4.0	6.2	1.0	7.1	1.0	7.9	ns
		C <sub>L</sub> = 15 pF	2.5	4.5	6.7	1.0	7.9	1.0	8.7	ns
		C <sub>L</sub> = 30 pF	3.3	5.6	8.2	1.5	10.0	1.5	11.0	ns
V <sub>CC</sub> = 2.	3 V to 2.7 V; V <sub>I</sub>	= 3.0 V to 3.6 V								
t <sub>pd</sub>	propagation	A, B, C to Y; see Fig. 12 [2]								
	delay	C <sub>L</sub> = 5 pF	1.4	3.2	4.9	0.5	5.5	0.5	6.1	ns
		C <sub>L</sub> = 10 pF	1.8	3.7	5.7	1.0	6.5	1.0	7.2	ns
		C <sub>L</sub> = 15 pF	2.2	4.2	6.3	1.0	7.4	1.0	8.2	ns
		C <sub>L</sub> = 30 pF	3.0	5.4	7.8	1.5	9.5	1.5	10.5	ns
V <sub>CC</sub> = 3.	0 V to 3.6 V; V <sub>I</sub>	= 1.65 V to 1.95 V		•		'				
t <sub>pd</sub>	propagation delay	A, B, C to Y; see <u>Fig. 12</u> [2]								
		C <sub>L</sub> = 5 pF	2.0	2.9	3.9	0.5	8.0	0.5	8.8	ns
		C <sub>L</sub> = 10 pF	2.5	3.5	4.6	1.0	8.5	1.0	9.4	ns
		C <sub>L</sub> = 15 pF	2.8	3.9	5.2	1.0	9.1	1.0	10.1	ns
		C <sub>L</sub> = 30 pF	3.6	5.1	6.6	1.5	9.8	1.5	10.8	ns
V <sub>CC</sub> = 3.	0 V to 3.6 V; V <sub>I</sub>	= 2.3 V to 2.7 V		•		_	<b>'</b>		<b>'</b>	
t <sub>pd</sub>	propagation	A, B, C to Y; see Fig. 12 [2]								I
	delay	C <sub>L</sub> = 5 pF	1.6	2.8	4.2	0.5	5.3	0.5	5.9	ns
		C <sub>L</sub> = 10 pF	2.0	3.4	4.9	1.0	6.1	1.0	6.8	ns
		C <sub>L</sub> = 15 pF	2.3	3.9	5.5	1.0	6.8	1.0	7.5	ns
		C <sub>L</sub> = 30 pF	3.1	5.0	6.9	1.5	8.5	1.5	9.4	ns
V <sub>CC</sub> = 3.	0 V to 3.6 V; V <sub>I</sub>	= 3.0 V to 3.6 V		'		·		<b>'</b>	<u> </u>	
t <sub>pd</sub>	propagation	A, B, C to Y; see Fig. 12 [2]								T
	delay	C <sub>L</sub> = 5 pF	1.3	2.8	4.2	0.5	4.7	0.5	5.2	ns
		C <sub>L</sub> = 10 pF	1.7	3.3	4.9	1.0	5.7	1.0	6.3	ns
		C <sub>L</sub> = 15 pF	2.0	3.8	5.5	1.0	6.2	1.0	6.9	ns
		C <sub>L</sub> = 30 pF	2.8	4.9	7.0	1.5	7.8	1.5	8.6	ns
T <sub>amb</sub> = 2	25 °C	•		<u>'</u>				1		
C <sub>PD</sub>	power	$f_i = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$ [3]								
	dissipation	V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
	capacitance	V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.3	-	-	-	-	-	pF

<sup>[1]</sup> All typical values are measured at nominal V<sub>CC</sub>.

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

 <sup>[2]</sup> t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>
 [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
 P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> × N + Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where:

#### Low-power configurable gate with voltage-level translator

### 11.1. Waveforms and test circuit

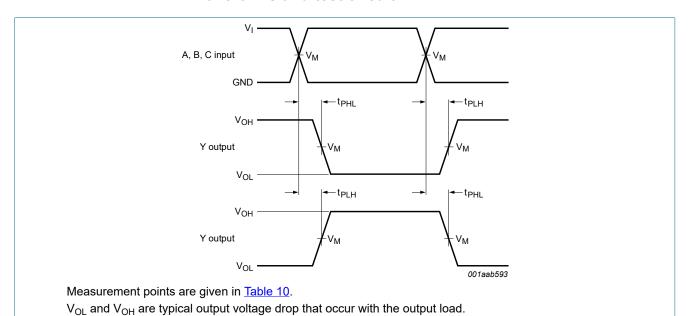
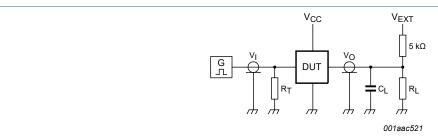


Fig. 12. Input A, B and C to output Y propagation delay times

**Table 10. Measurement points** 

Supply voltage	Output	Input		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$
2.3 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>I</sub>	1.65 V to 3.6 V	≤ 3.0 ns



Test data is given in Table 11.

Definitions for test circuit:

 $R_L$  = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

<sup>[1]</sup> For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ .

For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1  $M\Omega$ .

### Low-power configurable gate with voltage-level translator

# 12. Package outline

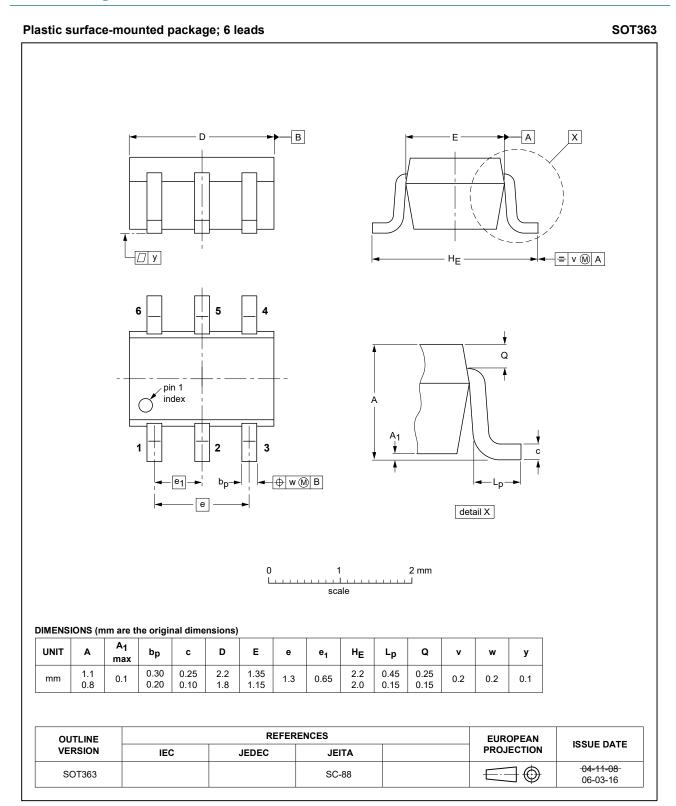


Fig. 14. Package outline SOT363 (SC-88)

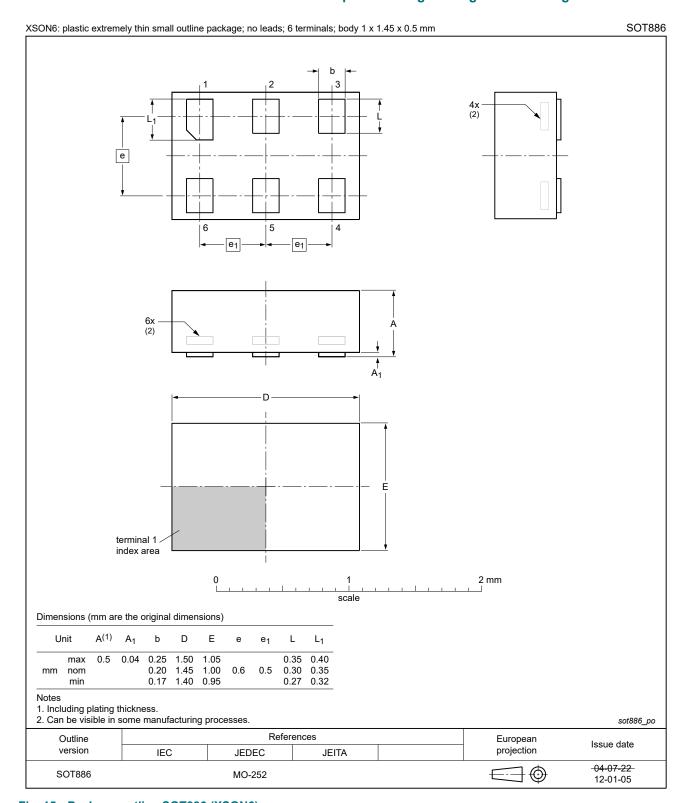


Fig. 15. Package outline SOT886 (XSON6)

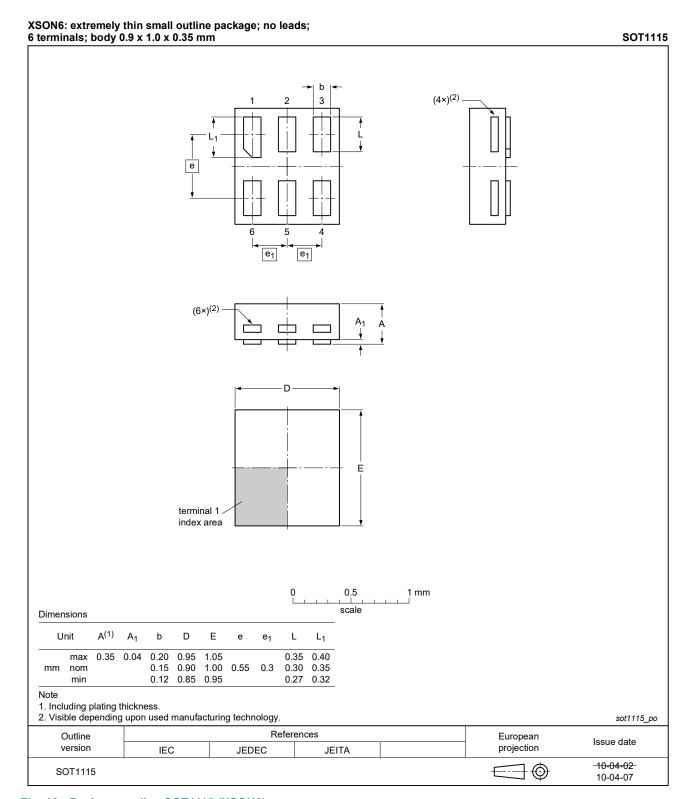


Fig. 16. Package outline SOT1115 (XSON6)

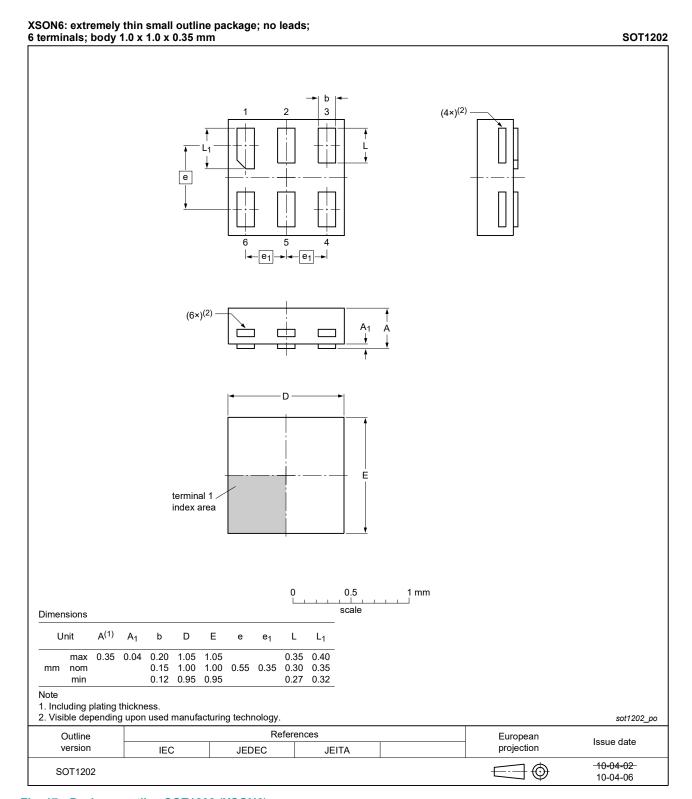


Fig. 17. Package outline SOT1202 (XSON6)

### Low-power configurable gate with voltage-level translator

# 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T57 v.6	20210526	Product data sheet	-	74AUP1T57 v.5
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP1T57GF (SOT891 / XSON6) removed.</li> <li>Section 1 and Section 2 updated.</li> <li>Section 8: Derating values for Ptot total power dissipation updated.</li> </ul>			
74AUP1T57 v.5	20120815	Product data sheet	-	74AUP1T57 v.4
Modifications:	Package outline drawing of SOT886 (Fig. 15) modified.			
74AUP1T57 v.4	20111201	Product data sheet	-	74AUP1T57 v.3
74AUP1T57 v.3	20100721	Product data sheet	-	74AUP1T57 v.2
74AUP1T57 v.2	20090803	Product data sheet	-	74AUP1T57 v.1
74AUP1T57 v.1	20080103	Product data sheet	-	-

#### Low-power configurable gate with voltage-level translator

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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